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APPLICATION NO. FILING	DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/604,010 06/20	/2003	STEVEN J. SEIPP	FIS920030142US1	1009
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CANTOR COLBURN LLI 55 GRIFFIN ROAD SOUT	ΓH .	oL	EXAMINER  STOCK JR, GORDON J  ART UNIT PAPER NUMBER  2877	GORDON J
BLOOMFIELD, CT 06002	<u>:</u>		ART UNIT	PAPER NUMBER
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SHORTENED STATUTORY PERIOD OF I	RESPONSE	MAIL DATE	DELIVERY MODE	
3 MONTHS		04/23/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

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	Application No.	Applicant(s)					
·	10/604,010	SEIPP, STEVEN J.					
Office Action Summary	Examiner	Art Unit					
	Gordon J. Stock	2877					
The MAILING DATE of this communication Period for Reply	appears on the cover sheet	with the correspondence address					
A SHORTENED STATUTORY PERIOD FOR RE WHICHEVER IS LONGER, FROM THE MAILING  - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory per  - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the meanned patent term adjustment. See 37 CFR 1.704(b).	COMMUNICATION OF THIS	NICATION. a reply be timely filed  ONTHS from the mailing date of this communication ABANDONED (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on 02	2 February 2007.						
2a)⊠ This action is <b>FINAL</b> . 2b)☐ T	This action is <b>FINAL</b> . 2b) This action is non-final.						
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
closed in accordance with the practice unde	er <i>Ex parte Quayle</i> , 1935 C	i.D. 11, 453 O.G. 213.					
Disposition of Claims							
4)⊠ Claim(s) <u>1-7 and 9-20</u> is/are pending in the	application.						
4a) Of the above claim(s) is/are without							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-7 and 9-20</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction an	id/or election requirement.						
Application Papers							
9)☐ The specification is objected to by the Exam	niner.						
10)⊠ The drawing(s) filed on <u>08 February 2006</u> is							
Applicant may not request that any objection to							
Replacement drawing sheet(s) including the cor							
11)☐ The oath or declaration is objected to by the	e Examiner. Note the attacr	ned Office Action of form P10-132.					
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for fore a) All b) Some * c) None of:	eign priority under 35 U.S.C	5. § 119(a)-(d) or (f).					
<ol> <li>Certified copies of the priority docum</li> </ol>	ents have been received.						
<ol><li>Certified copies of the priority docum</li></ol>							
3. Copies of the certified copies of the p		en received in this National Stage					
application from the International But			4				
* See the attached detailed Office action for a	list of the certified copies if	ot received.					
Attachment(s)	•						
1) Notice of References Cited (PTO-892)		w Summary (PTO-413)					
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	′	No(s)/Mail Date of Informal Patent Application (PTO-152)					
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB Paper No(s)/Mail Date	6) Other:						

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#### **DETAILED ACTION**

1. The Amendment received on February 2, 2007 has been entered into the record.

## Claim Rejections - 35 USC § 101

2. 35 U.S.C. 101 reads as follows:

Whoever invents or discovers any new and useful process, machine, manufacture, or composition of matter, or any new and useful improvement thereof, may obtain a patent therefor, subject to the conditions and requirements of this title.

3. Claims 1, 4-12, and 14-20 are rejected under 35 U.S.C. 101 because the claimed invention is directed to non-statutory subject matter.

Claims 1, 4-12, and 14-20 are directed to a judicial exception; as such, pursuant to the Interim Guidelines on Patent Eligible Subject Matter (MPEP 2106), the claims must have either physical transformation and/or a useful, concrete and tangible result. The claims fail to include transformation from one physical state to another. Although, the claims appear useful and concrete, there does not appear to be a tangible result claimed. Merely 'determining substrate position (the determining step is an abstract idea without a tangible result of claim 1 that appears to comprise solving of a set of equations as demonstrated by the use of software in paragraph 0035 of Applicant's disclosure) and 'locating a third point of interest (the locating step is an abstract idea without a tangible result of claim 12 that appears to comprise solving a set of equations as demonstrated by the use of software in paragraph 0035 of Applicant's disclosure) would not appear to be sufficient to constitute a tangible result, since the outcome of the determining/locating has not been used in a disclosed practical application nor made available in such a manner that its usefulness in a disclosed practical application can be realized. As such, the subject matter of the claims is not patent eligible. Claims 4-11, 14-20 are rejected for

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depending upon a rejected base claim; wherein **claims 4-11, 14-20** further limiting of the parent claim still does not have a tangible result.

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 1-5, 10, and 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gotoh et al. (6,225,011)—previously cited in view of Berman (6,347,291)—previously cited.

As for **claim 1**, Gotoh in a method for manufacturing semiconductor devices discloses the following: disposing a patterned substrate in an exposure system with an alignment routine (col. 2, lines 10-15 and 20-25); locating a first point of interest on the patterned substrate (Fig. 5a: 8 and Fig. 5b: one array of marks in 5 different exposure fields); scanning a first area proximate the first point of interest for a first unique feature (col. 2, lines 24-25); defining a periodicity for the patterned substrate as defined by a constant pitch from a mask (col. 2, lines 20-22); locating a second point of interest based on the periodicity (Fig. 5a: 8, a second mark and Fig. 5b: a second array of marks in 5 different exposure fields); scanning a second area proximate the second point of interest for a second unique feature corresponding to the first unique feature (again, col. 2, lines 24-25 with Fig. 5a: 8, a second mark in first array of distortion marks and Fig. 5b: a second array of marks in 5 different exposure fields); gathering alignment data from at least scanning the first and second areas (col. 2, lines 24-26). As for 'determining substrate position relative to the exposure system from alignment data of at least the first and

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second scanned areas' Gotoh does not explicitly state this in the embodiments representative of Fig. 5a and Fig. 5b but he suggests it (col. 2, lines 25-30). And he teaches that there are alignment marks in each scanned area, at least four alignment marks to determine substrate position(Fig. 2: 2; col. 1, lines 40-55). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to determine substrate position relative to the exposure system for at least two arrays of distortion marks with alignment marks in order to have proper alignment between substrate and mask in order to correctly evaluate the positions of the distortion marks relative to the exposure system by knowing the substrate position.

As for a stage, Gotoh is silent in the particular prior art embodiments, but he teaches a stage in Fig. 10 with a stage control unit (Fig. 10: 18). It would be obvious to one of ordinary skill in the art at the time the invention was made to have the system comprise a stage in order to provide support and relative positioning means for the wafer.

Gotoh is silent concerning 'the first unique feature is saved as an alignment image for use in locating the second unique feature in the second area.' However, Berman in a substrate position location system teaches using alignment images of structures in an intermediate area in order to determine the absolute position of a target structure in another area (col. 2, lines 20-35). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to save the first unique feature as an alignment image in order to determine the location of a neighboring feature in another area through shape comparison.

As for **claim 2**, Gotoh in view of Berman discloses everything as above (see **claim 1**). In addition, Gotoh discloses aligning the substrate relative to the exposure system (col. 2, lines 25-30 and col. 1, lines 45-53).

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As for **claim 3**, Gotoh in view of Berman discloses everything as above (see **claim 1**). In addition, Gotoh discloses exposing the wafer with the exposure system (col. 2, lines 23-24).

As for **claim 4**, Gotoh in view of Berman discloses everything as above (see **claim 1**). In addition, Gotoh discloses that the substrate is a semiconductor wafer (Fig. 5b: 1).

As for **claim 5**, Gotoh in view of Berman discloses everything as above (see **claim 1**). In addition, Gotoh discloses the first and second unique features include alignment marks on the substrate (col. 2, line 12-15; Fig. 5a: 8; Fig. 5b: 8a).

As for **claim 10**, Gotoh in view of Berman discloses everything as above (see **claim 1**). In addition, Gotoh discloses a plurality of exposure fields (Fig. 5b: 8a); wherein the method comprises at least one of measuring at least one point of interest in each field of a plurality of exposure fields (col. 2, lines 18-30).

As for **claim 11**, Gotoh in view of Berman discloses everything as above (see **claim 1**). In addition, Gotoh discloses the substrate comprising a plurality of exposure fields, wherein each exposure field comprises at least one unique feature (Fig. 5b: 8a; wherein, each field comprising a plurality of distortion marks such as 8 from Fig. 5a).

6. Claims 6, 9, 12-16, 18-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gotoh et al. (6,225,011)—previously cited in view of Berman (6,347,291)—previously cited further in view of Utsunomiya (6,801,825)—previously cited.

As for **claim 6**, Gotoh in view of Berman discloses everything as above (see **claim 1**). Gotoh is silent concerning mapping first and second points of interests and corresponding unique features to determine an orientation of substrate. However, Utsunomiya in a semiconductor exposure apparatus management system teaches mapping features (Figs. 2, 3a, 3b, 3c, Fig. 12a:

1113). Therefore, it would be obvious to one skilled in the art at the time the invention was made to map the points of interests and marks of wafer to determine orientation error of the wafer in order correct for each measurement coordinate on the wafer.

As for **claim 9**, Gotoh in view of Berman discloses everything as above (see **claim 1**). Gotoh is silent concerning a path for automatic correction should the alignment routine fail to align, but suggests an automatic correction scheme (Fig. 8, 103-104). However, Utsunomiya in a semiconductor exposure apparatus management system teaches an automatic correction (Fig. 12b: feedback from 1119 to 1120 to B). Therefore, it would be obvious to one skilled in the art at the time the invention was made to provide automatic correction should alignment routine fail to align in order to provide iterative feedback to improve alignment accuracy.

As for **claim 12**, Gotoh in a method of manufacturing semiconductor devices discloses the following: defining a point of interest for each segment of the patterned substrate (Fig. 5a: 8; Fig. 5b: 8 wherein, at least one point of interest, an exposure field, in at least 5 segments comprising an exposure field consisting of an array of distortion marks); locating a first point of interest in a first segment as demonstrated through scanning the distortion marks; wherein, at least a first area proximate the first point of interest for a first unique feature, a distortion mark, is scanned (col. 2, lines 24-25); defining a periodicity for the patterned substrate as defined by a constant pitch from a mask (col. 2, lines 20-22); locating a second point of interest in a second segment based on the periodicity; wherein a second area proximate the second point of interest for a second unique feature, a second distortion mark of a second array of marks, corresponding to the first unique feature (col. 2, lines 24-25; Fig. 5b: 8a); measuring the second point of interest (col. 2, lines 25-30); locating a third point of interest in a third segment based on the periodicity

(Fig. 5b: 8a—third exposure field of five exposure fields). As for saving a scanned image of the first area and mapping the alignment of the substrate with respect to the tooling in which it was disposed, Gotoh is silent. However, Utsunomiya in a semiconductor exposure apparatus management system teaches mapping features (Figs. 2, 3a, 3b, 3c, Fig. 12a: 1113) and demonstrates saving an image of area of measurement for reference (Fig 7; col. 5, lines 40-50). Therefore, it would be obvious to one skilled in the art at the time the invention was made to map the points of interests and marks of wafer to determine orientation error of the wafer in order correct for each measurement coordinate on the wafer. And it would be obvious to one skilled in the art at the time the invention was made to save a scanned image of the first area of measurement in order to determine distortion by measuring displacement at a plurality of points in the image.

Gotoh is silent concerning 'the first unique feature is saved as an alignment image for use in locating the second unique feature in the second area.' However, Berman in a substrate position location system teaches using alignment images of structures in an intermediate area in order to determine the absolute position of a target structure in another area (col. 2, lines 20-35). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to save the first unique feature as an alignment image in order to determine the location of a neighboring feature in another area through shape comparison.

Also as for a 'method of aligning a patterned substrate and measuring the same,' Gotoh does not explicitly state this in the embodiments representative of Fig. 5a and Fig. 5b but he suggests it (col. 2, lines 25-30). And he teaches that there are alignment marks in each scanned area, at least four alignment marks to determine substrate position (Fig. 2: 2; col. 1, lines 40-55).

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Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to determine substrate position relative to the exposure system for at least two arrays of distortion marks with alignment marks in order to have proper alignment between substrate and mask in order to correctly evaluate the positions of the distortion marks relative to the exposure system by knowing the substrate position.

As for **claim 13**, Gotoh in view of Berman and Utsonimya discloses everything as above (see **claim 12**). In addition, Gotoh discloses exposing the wafer with the exposure system (col. 2, lines 23-24).

As for **claim 14**, Gotoh in view of Berman and Utsonimya discloses everything as above (see **claim 12**). In addition, Gotoh discloses the substrate is a semiconductor wafer (Fig. 5b: 1).

As for **claim 15**, Gotoh in view of Berman and Utsonimya discloses everything as above (see **claim 12**). In addition, Gotoh discloses the first and second unique features include alignment marks on the substrate (col. 2, line 12-15; Fig. 5a: 8; Fig. 5b: 8a).

As for **claim 16**, Gotoh in view of Berman and Utsonimya discloses everything as above (see **claim 12**). In addition, Gotoh discloses the alignment data determines an orientation of the substrate relative to the tooling, exposure system (col. 2, lines 25-31).

As for **claim 18**, Gotoh in view of Berman and Utsonimya discloses everything as above (see **claim 12**). In addition, Gotoh discloses a plurality of exposure fields each corresponding a to segment of the wafer (Fig. 5b: 8a); wherein the method comprises at least one of measuring at least one point of interest in each field of a plurality of exposure fields (col. 2, lines 18-30).

As for claim 19, Gotoh in view of Berman and Utsonimya discloses everything as above (see claim 12). In addition, Gotoh discloses the substrate comprising a plurality of exposure

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fields corresponding to a segment of the wafer, wherein each exposure field comprises at least one unique feature (Fig. 5b: 8a; wherein, each field comprising a plurality of distortion marks such as 8 from Fig. 5a).

As for **claim 20**, Gotoh in view of Berman and Utsonimya discloses everything as above (see **claim 12**). In addition, Gotoh discloses that each unique feature, distortion mark, is similarly oriented with respect to each corresponding segment, area on the wafer (Fig. 5a: 8; Fig. 5b: 8a with five different segments with each segment having a exposure field).

7. Claim 7 is rejected under 35 U.S.C. 103(a) as being unpatentable over Gotoh et al. (6,225,011)—previously cited in view of Berman (6,347,291) further in view of Wang et al. (4,327,292)—previously cited.

As for claim 7, Gotoh in view of Berman discloses everything as above (see claim 1). In addition, Gotoh discloses that the fields are scanned (Fig. 5a: 8; Fig. 5b: 8a; col. 2, lines 24-25). Gotoh is silent concerning raster scanning around the first point of interest until the first unique feature is within a field of view. However, Wang teaches raster scanning for alignment (col. 11, lines 25-45). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to raster scan the wafer around the area of interest until the first unique feature is within a field of view in order to determine a difference between the scan signal with background and the scan signal of the mark itself by observing changes in the scan signal's intensity over the mark versus proximate the mark thereby differentiating between the mark of interest and the background.

8. Claim 17 is rejected under 35 U.S.C. 103(a) as being unpatentable over Gotoh et al. (6,225,011)—previously cited in view of Berman (6,347,291) further in view of Utsunomiya (6,801,825)—previously cited and further in view of Wang et al. (4,327,292)—previously cited.

As for **claim 17**, Gotoh in view of Berman and Utsunomiya discloses everything as above (see **claim 12**). In addition, Gotoh discloses the fields are scanned (Fig. 5a: 8; Fig. 5b: 8a; col. 2, lines 24-25). Gotoh is silent concerning raster scanning around the first point of interest until the first unique feature is within a field of view. However, Wang teaches raster scanning for alignment (col. 11, lines 25-45). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to raster scan the wafer around the area of interest until the first unique feature is within a field of view in order to determine a difference between the scan signal with background and the scan signal of the mark itself by observing changes in the scan signal's intensity over the mark versus proximate the mark thereby differentiating between the mark of interest and the background.

#### Response to Arguments

9. Applicant's arguments filed February 2, 2007 have been fully considered but they are not persuasive. In regards to the argument on page 8 of Remarks that the claim as a whole includes preamble language, the Examiner has not deemed the final result of the claims rejected under 35 U.S.C. 101 as the preamble language (see rejections under 35 U.S.C. 101 above). In addition, claim 1's preamble 'a method of aligning a substrate to an exposure system' is not referred back to by the limitations, and therefore, has not been given patentable weight because it has been held that a preamble is denied the effect of a limitation where the claim following the preamble

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is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951). As well claim 12's preamble reads 'a method of aligning a patterned substrate having a plurality of segments and measuring the same.' If the Examiner followed the argument of applicant using the preamble as a final result, then 'measuring the same' appears to be an abstraction.

In regards to the argument that the Examiner has not identified and explained in the record the basis for why the claim is for an abstract idea with no practical application (see rejection under 35 U.S.C. 101) and that the mention of 'solving a system of equations' would not appear to be sufficient to support the Examiner's conclusion that the final result of the claims Examiner disagrees. Both 'determining/locating' appear to be algorithmic in nature with solving of equations as mentioned in paragraph 0035 of Applicant's disclosure through the use of software. Again, merely 'determining/locating' would not appear to be sufficient to constitute a tangible result, since the outcome of the 'determining/locating' has not been used in a disclosed practical application nor made available in such a manner that its usefulness in a disclosed practical application can be realized. Also as for the argument on page 9 that 'the location of a substrate position' is a real world result' that may be the case; however, the claimed result in claim 12 of 'locating' does not use the location in a disclosed application nor conveys the location in a manner that can be used. As such the result cannot be said to be tangible. In addition, 'locating' is defined as comprising 'detecting (paragraph 0035)' which appears also to be an abstraction without a tangible result.

As for the argument on page 11 of Remarks in regards to the rejection of the claims under 35 U.S.C. 103(a) with Gotoh, Examiner disagrees. Specifically, the argument that Gotoh fails to

teach 'scanning a second area proximate the second point of interest for a second unique feature corresponding to the first unique feature, wherein the first unique feature is saved as an alignment image for use in locating the second unique feature in the second area; gathering alignment data from at least scanning the first and second areas, and determining substrate position relative to the exposure system from alignment data of at least the first and second scanned areas' Examiner disagrees (see rejection of claim 1) because in response to applicant's arguments against the references individually, one cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See In re Keller, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); In re Merck & Co., 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986). In addition, Examiner would like to point out that in claim 1 the limitation 'determining substrate position relative to the exposure system from alignment data of at least the first and second scanned areas' does not exclude alignment data gathered from scanning two alignment marks that are in the scanned area of the distortion marks (Gotoh: Figs. 5a and 5b with Fig. 2; col. 1, lines 40-55; col. 2, lines 15-30). In addition, for claim 1, the steps of disposing, locating, scanning a first area, defining a periodicity, locating a second point of interest, and scanning a second area proximate the second point of interest does not preclude an alignment routine for the exposure beam to the wafer (see rejection of claim 1 above). Also the gathering alignment data from at least scanning the first and second areas does not preclude gathering alignment data from either scanning areas comprising both distortion and alignment marks for either substrate alignment or exposure beam alignment.

10. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

# Fax/Telephone Numbers

If the applicant wishes to send a fax dealing with either a proposed amendment or a discussion with a phone interview, then the fax should:

- 1) Contain either a statement "DRAFT" or "PROPOSED AMENDMENT" on the fax cover sheet; and
  - 2) Should be unsigned by the attorney or agent.

This will ensure that it will not be entered into the case and will be forwarded to the examiner as quickly as possible.

Papers related to the application may be submitted to Group 2800 by Fax transmission. Papers should be faxed to Group 2800 via the PTO Fax machine located in Crystal Plaza 4. The form of such papers must conform to the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The CP4 Fax Machine number is: (571) 273-8300

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Gordon J. Stock whose telephone number is (571) 272-2431.

The examiner can normally be reached on Monday-Friday, 10:00 a.m. - 6:30 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Gregory J. Toatley, Jr., can be reached at 571-272-2800 ext 77.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private Pair system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

April 12, 2007

Gregory J. Toatley, Jr. Supervisory Patent Examiner Art Unit 2877